

Docket No.: 21737-00013-US
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Katsuki Hazama

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Application No.: 09/438,295

Art Unit: 2135

AUG 18 2004

Filed: November 12, 1999

Examiner: L. Hua

OFFICIAL

For: MULTILEVEL SEMICONDUCTOR MEMORY
WRITE/ READ METHOD
THERETO/THEREFROM AND STORAGE
MEDIUM STORING WRITE/READ PROGRAM

AMENDMENT AFTER FINAL ACTION (37 C.F.R. SECTION 1.116)

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated May 18, 2004 (Paper No. 9), favorable reconsideration of the application is requested.

Please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 18 of this paper.